AMENDMENTS TO THE ABSTRACT

At page 27, please delete the current Abstract and replace it with the following

Abstract:

A method for reading a non-volatile memory arranged in columns and rows which

reduces adjacent cell coupling, sometimes referred to as the Yupin effect. The method

includes the steps of: selecting a bit to be read in a word-line; reading an adjacent the word

line written after word line; and reading the selected bit in the word line by selectively

adjusting at least one read parameter. In one embodiment, the read parameter is the sense

voltage. In another embodiment, the read parameter is the pre-charge voltage. In yet another

embodiment, both the sense and the pre-charge voltage are adjusted.

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